

KPBA-3010SYKCGKC





DESCRIPTIONS

- The Super Bright Yellow device is made with AlGaInP (on GaAs substrate) light emitting diode chip
- . The Green source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- · Electrostatic discharge and power surge could damage the LEDs
- . It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- · All devices, equipments and machineries must be electrically grounded

FEATURES

- 3.0 x 2.0 x 1.0 mm right angle SMD LED, 1.0 mm thickness
- · Low power consumption
- · Wide viewing angle
- · Ideal for backlight and indicator
- · Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Tinned pads for improved solderability
- RoHS compliant

APPLICATIONS

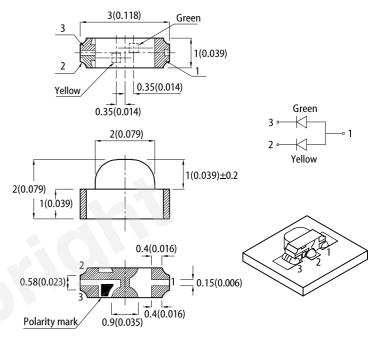
- Backlight
- · Status indicator
- Home and smart appliances
- · Wearable and portable devices
- · Healthcare applications

ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices

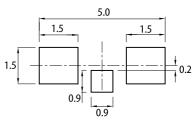


PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units: mm; tolerance: ± 0.1)



- 1. All dimensions are in millimeters (inches)
- Tolerance is ±0.15(0.006") unless otherwise noted.
 The specifications, characteristics and technical data described in the datasheet are subject to
- change without prior notice.

 The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color	Lens Type	Iv (mcd) @ 20mA [2]		Viewing Angle [1]
Part Number	(Material)		Min.	Тур.	201/2
KPBA-3010SYKCGKC	Super Bright Yellow (AlGaInP)	Water Clear	80	120	440°
NEDA-30 103 INCONC	Green (AlGalnP)	vvaici Cleal	40	70	140°

Notes.

1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

2. Luminous intensity / luminous flux: +/-15%.

3. Luminous intensity value is traceable to CIE127-2007 standards.





ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Va	lue	Unit
- 	Cyzc.		Тур.	Max.	3.110
Wavelength at Peak Emission I _F = 20mA	λ_{peak}	Super Bright Yellow Green	590 574	-	nm
Dominant Wavelength I _F = 20mA	λ _{dom} ^[1]	Super Bright Yellow Green	590 570	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	Δλ	Super Bright Yellow Green	20 20	-	nm
Capacitance	С	Super Bright Yellow Green	20 15	-	pF
Forward Voltage I _F = 20mA	V _F ^[2]	Super Bright Yellow Green	2.0 2.1	2.5 2.5	V
Reverse Current (V _R = 5V)	I _R	Super Bright Yellow Green	-	10 10	uA

Notes:

ABSOLUTE MAXIMUM RATINGS at T₄=25°C

Parameter	Symbol	Value		Unit
· Granisto.	Cymbo.	Super Bright Yellow	Green	- O.III
Power Dissipation	P _D	75	75	mW
Reverse Voltage	V _R	5	5	V
Junction Temperature	TJ	115	115	°C
Operating Temperature	Тор	-40 To +85		
Storage Temperature	T_{stg}	-40 To +85		°C
DC Forward Current	I _F	30	30	mA
Peak Forward Current	I _{FM} ^[1]	175	150	mA
Electrostatic Discharge Threshold (HBM)	-	3000	3000	V

Notes:
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

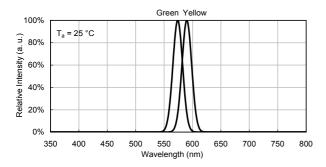


^{1.} The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd:±1nm.)
2. Forward voltage: ±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

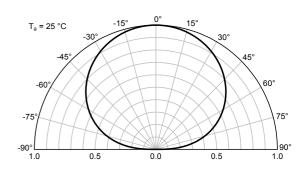


TECHNICAL DATA

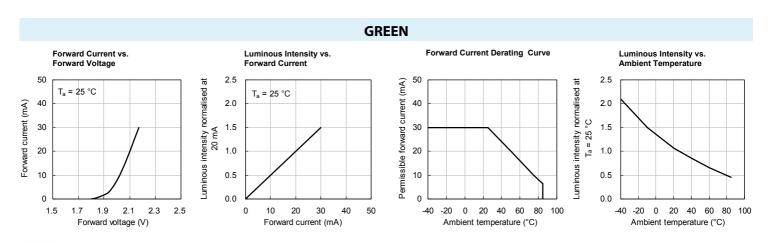
RELATIVE INTENSITY vs. WAVELENGTH



SPATIAL DISTRIBUTION

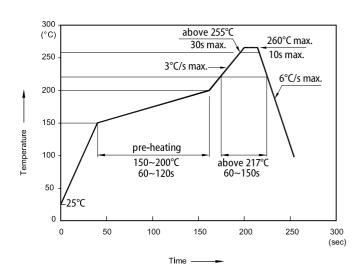


SUPER BRIGHT YELLOW Forward Current vs. Forward Voltage Luminous Intensity vs. Forward Current Derating Curve Luminous Intensity vs. **Forward Current Ambient Temperature** 50 2.5 2.5 Luminous intensity normalised at -uminous intensity normalised at Permissible forward current (mA) T_a = 25 °C T_a = 25 °C 2.0 40 2.0 40 Forward current (mA) ပွ 30 30 1.5 1.5 20 mA $T_a = 25$ ° 20 1.0 20 1.0 10 0.5 10 0.5 0.0 0 n 0.0 2.1 2.3 20 -40 -20 0 20 40 60 80 100 -40 -20 0 20 40 60 80 100 Forward voltage (V) Forward current (mA) Ambient temperature (°C) Ambient temperature (°C)





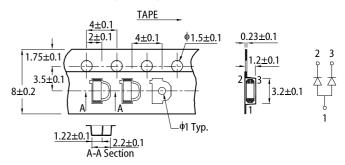
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



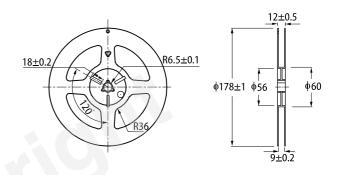
- Don't cause stress to the LEDs while it is exposed to high temperature
 The maximum number of reflow soldering.
- The maximum number of reflow soldering passes is 2 times.

 Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

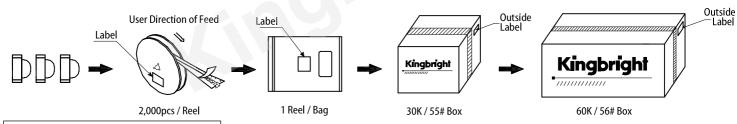
TAPE SPECIFICATIONS (units: mm)



REEL DIMENSION (units: mm)



PACKING & LABEL SPECIFICATIONS





PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only.

 The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.

 The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening
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